# RENESAS

# R2A20133DSP

# Critical Conduction Mode PFC Control IC

R03DS0052EJ0300 Rev.3.00 Feb 27, 2013

Datasheet

## Description

The R2A20133D controls a boost converter to provide an active power factor correction.

The R2A20133D adopts critical conduction mode for power factor correction and realizes high efficiency and a low switching noise by zero current switching.

Because the zero current is detected by using the GND current, the ZCD Auxiliary winding is unnecessary.

The feedback loop open detection, two mode overvoltage protection, overcurrent protection are built in the R2A20133D, and can constitute a power supply system of high reliability with few external parts.

#### Features

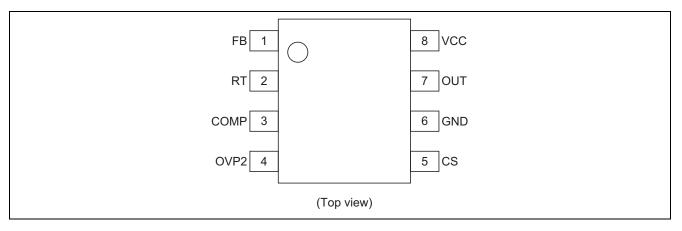
- Absolute Maximum Ratings
  - Supply voltage Vcc: 24 V
  - Operating junction temperature Tjopr: –40 to +150°C
- Electrical characteristics
  - UVLO operation start voltage VH: 9.5 V  $\pm$  0.7 V
  - UVLO operation shutdown voltage VL: 8.5 V  $\pm$  0.4 V
  - UVLO hysteresis voltage Hysuvl:  $1.0 \text{ V} \pm 0.4 \text{ V}$
- Functions
  - Boost converter control with critical conduction mode
  - Two mode overvoltage protection and OVP2
    Mode 1: Dynamic OVP corresponding to a voltage rise by load change
    Mode 2: Static OVP corresponding to overvoltage in stable.
    OVP2: OVP2 senses the PFC output voltage by independence pin.
  - Feedback loop, open detection
  - Overcurrent protection
  - Dynamic UVP corresponding to a voltage fall by load change
  - Frequency limiter, adjustable
  - Zero Current Detect (ZCD) delay time, adjustable
  - CS pin's open detection
  - Package lineup: Pb-free SOP-8 (JEDEC)

#### **Ordering Information**

Part No.	Package Name	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
R2A20133DSP#W5	—	PRSP0008DJ-A	SP	W (2,500 pcs/reel)



## **Pin Arrangement**

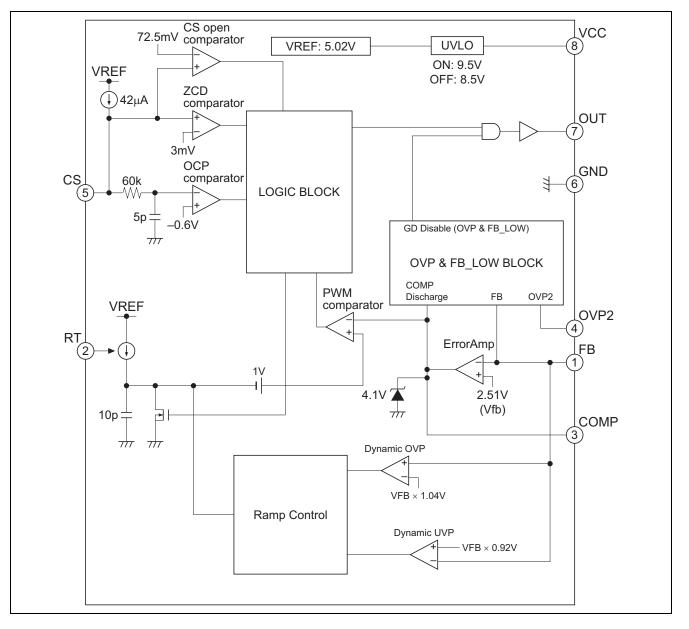


## **Pin Functions**

Pin No.	Pin Name	Function			
1	FB	Error amplifier input terminal			
2	RT	Max-ON time, ZCD-delay and Frequency limiter adjustment terminal			
3	COMP	Error amplifier output terminal			
4	OVP2	Over voltage detection terminal			
5	CS	Zero current detection and overcurrent detection input terminal			
6	GND	Ground			
7	OUT	Power MOSFET drive terminal			
8	VCC	Supply voltage terminal			



### **Block Diagram**





## **Absolute Maximum Ratings**

				$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit	Note
Supply Voltage	VCC	-0.3 to +24	V	
OUT terminal peak current	lpk-snk-out	+0.9	А	3
	lpk-src-out	-0.5		
OUT terminal DC current	ldc-snk-out	+100	mA	
	Idc-src-out	-50		
COMP terminal current	Icomp	+1	mA	
		-1		
RT terminal current	Irt	-50 to -2	μA	
Terminal voltage	Vt-group1	-0.3 to VCC	V	4
	Vt-group2	-0.3 to 5.3		5
CS terminal voltage	Vcs	-5 to +0.3	V	
Power dissipation	Pt	0.68	W	6
Operating junction temperature	Tj-opr	-40 to +150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. Rated voltages are with reference to the GND terminal.

2. For rated currents, inflow to the IC is indicated by (+), and outflow by (–).

3. Shows the transient current when driving a capacitive load.

- 4. This is the rated voltage for the following pins: OUT
- 5. This is the rated voltage for the following pins: FB, COMP, OVP2, RT

6.  $\theta_{ja} = 120^{\circ}$ C/W This value is a thing mounting on  $40 \times 40 \times 1.6$  [mm], a glass epoxy board of wiring density 10%.



## **Electrical Characteristics**

(	$T_0 = 25^{\circ}C$	VCC = 12 V	CS = 0.04 V	EP - 2V	COMD: Open	OVD2 - 1V	$RRT = 200 \text{ k}\Omega$
(	1a - 25 C,	, VCC = 12 V	, CS = 0.04 V	, ГD — 2 V,	COMF. Open	1, OVFZ - IV	, KK1 - 200 KS2)

	Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Supply	UVLO turn-on threshold	Vuvlh	8.8	9.5	10.2	V	
	UVLO turn-off threshold	Vuvll	8.1	8.5	8.9	V	
	UVLO hysteresis	Hysuvl	0.6	1.0	1.4	V	
	Standby current	Istby	_	100	200	μA	VCC = Vuvlh – 0.2 V
	Operating current	Icc	_	1.8	2.6	mA	
Error	Feedback voltage	Vfb	2.472	2.510	2.548	V	FB-COMP short
amplifier	Temperature stability	dVfb	_	±80	_	ppm/°C	Ta = -40 to +125°C *
	Input bias current	lfb	-0.40	-0.15	-0.05	μΑ	Measured pin: FB
	Open loop gain	Av	_	65	_	dB	*1
	Upper clamp voltage	Vclamp-comp	3.75	4.10	4.35	V	FB = 2.45 V COMP: Open
	Low voltage	VI-comp	—	0.1	0.3	V	FB = 3.0 V COMP: Open
	Source current1	Isrc-comp1	-13.5	-10	-6	μΑ	FB = 1.7 V COMP = 2.5 V
	Source current2	lsrc-comp2	lsrc-comp1 ×3.3	Isrc-comp1 ×3.0	Isrc-comp1 ×2.7	μΑ	FB = 1.5 V COMP = 2.5 V
	Sink current	Isnk-comp	6	10	13.5	μΑ	FB = 3.5 V COMP = 2.5 V
	Transconductance	gm	25	46	75	μS	FB = 2.45V ↔ 2.55 V COMP = 2.5 V
RT	RAMP offset voltage	Voff_ramp	_	1.0	_	V	*1
	RAMP amplitude	dVramp	2.90	3.1	3.3	V	*2
	RT voltage	V-rt	2.5	2.6	2.7	V	
	ZCD delay time	Zcd-delay	_	0.87	_	μS	RRT = 200 k $\Omega *^{1}$
	Maximum frequency	fmax	_	500	_	kHz	RRT = 200 k $\Omega *^{1}$
Zero	ZCD threshold voltage	Vzcd	1	3	6	mV	
current	Input bias current	lcs	-58	-42	-25	μA	Vcs = 0 V
detector	CS open detect threshold voltage	Vcs-open	45	72.5	130	mV	
Restart	Restart time delay	Tstart	75	150	330	μS	FB = 2.0 V COMP = 2.5 V

Notes: \*1 Design spec

\*2 dVramp = Vclamp\_comp - Voff\_ramp



## Electrical Characteristics (cont.)

(Ta = 25°C, VCC = 12 V, CS = 0.04 V, FB = 2 V, COMP: Open, OVP2 = 1 V, RRT = 200 kΩ)

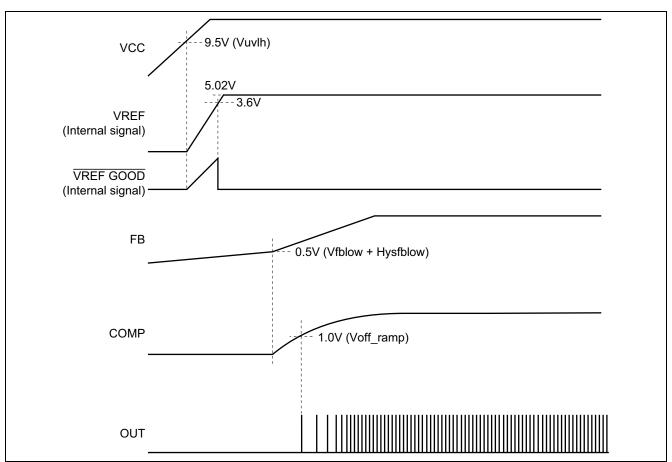
Item		Symbol	Min	Тур	Max	Unit	Test Conditions	
Out	Rise time	tr-out	-	35	100	ns	CL = 1000 pF 90%	
	Fall time	tf-out	-	35	100	ns	CL = 1000 pF	
	Out low voltage	Vol1-out	—	0.08	0.2	V	lsink = 20 mA	
		Vol2-out	—	0.05	0.7	V	VCC = 5 V, Isink = 10 mA	
	Out high voltage	Voh-out	11.5	11.8	_	V	Isource = -20 mA	
Over current protection	OCP threshold voltage	Vocp	-0.63	-0.6	-0.57	V		
Over & Under	Dynamic OVP threshold voltage	Vdovp	-	Vfb× 1.040	—	V	Measure FB * <sup>1</sup>	
voltage protection	Dynamic UVP threshold voltage	Vduvp	-	Vfb× 0.920	_	V	*1	
	Static OVP threshold voltage	Vsovp	Vfb× 1.075	Vfb× 1.090	Vfb× 1.105	V		
	Static OVP hysteresis	Hys-sovp	50	100	150	mV		
	FB low detect threshold voltage	Vfblow	0.25	0.3	0.35	V		
	FB low detect hysteresis	Hysfblow	0.16	0.20	0.24	V		
	OVP2 high threshold voltage	Vovp2-high	Vfb× 1.18	Vfb× 1.20	Vfb× 1.22	V	Measure OVP2	
	OVP2 low threshold voltage	Vovp2-low	0.1	0.2	0.3	V		
	OVP2 source current	lsrc-ovp2	-0.40	-0.15	-0.05	μA		

Note: \*1 Design spec

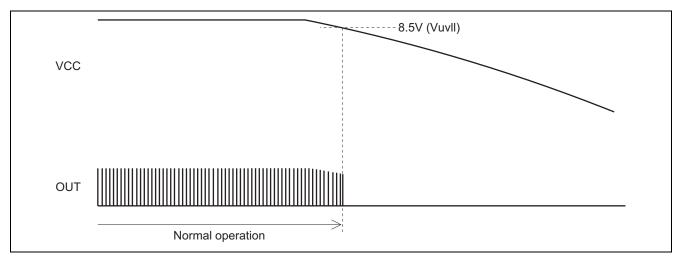


## Waveforms

#### 1. Start-up

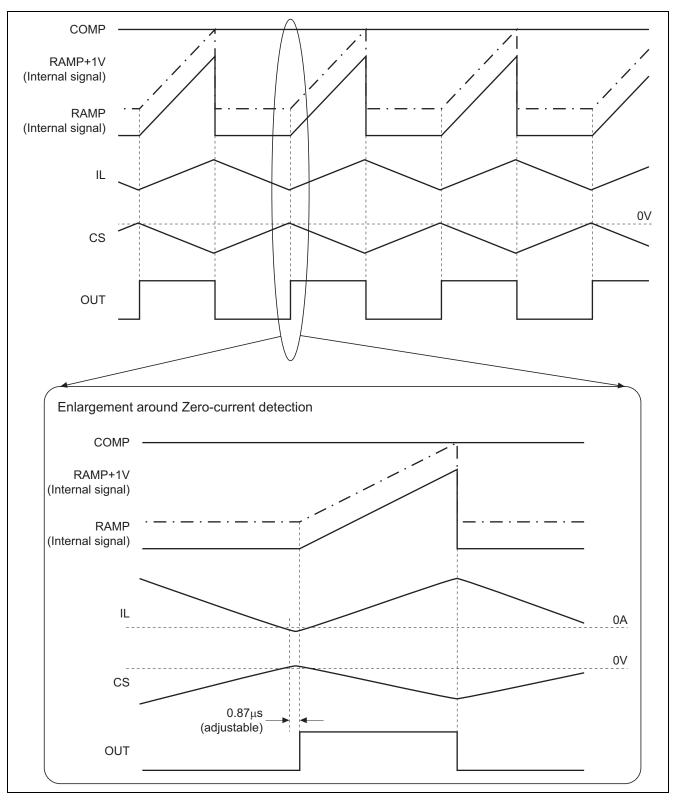


#### 2. Shut-down

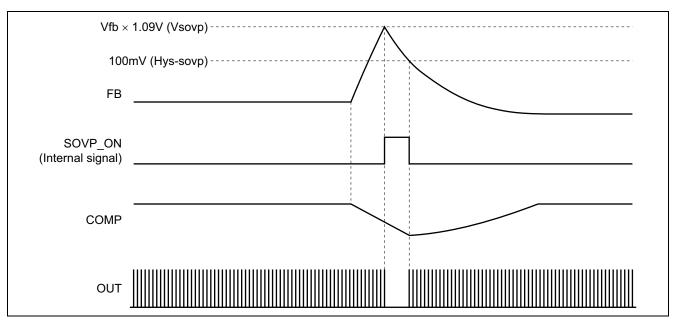




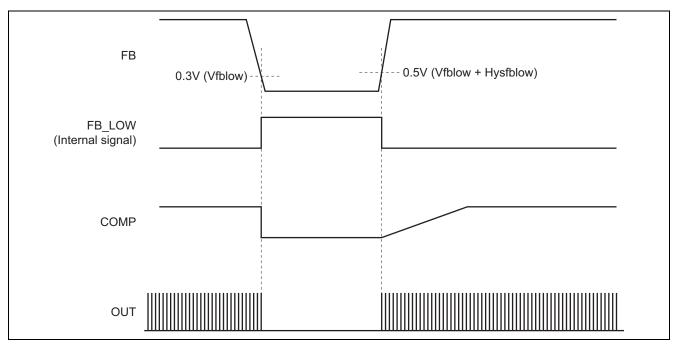
#### 3. Gate Drive Output



#### 4. Overvoltage Protection (SOVP)

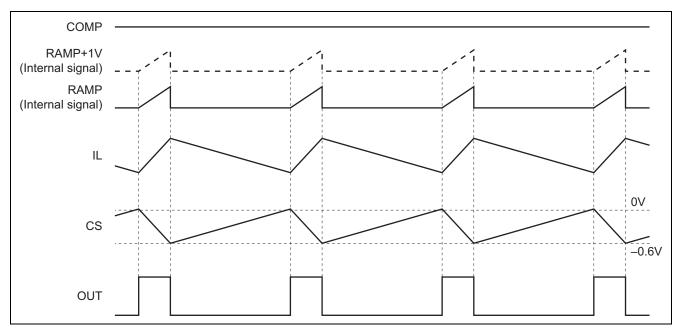


#### 5. FB Low Detection

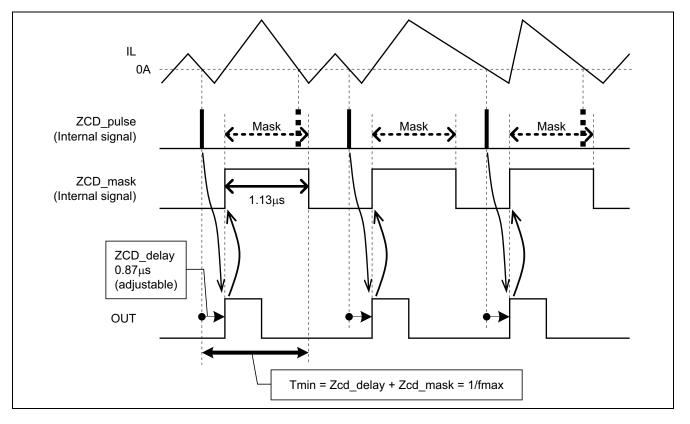




### 6. Overcurrent Protection (OCP)

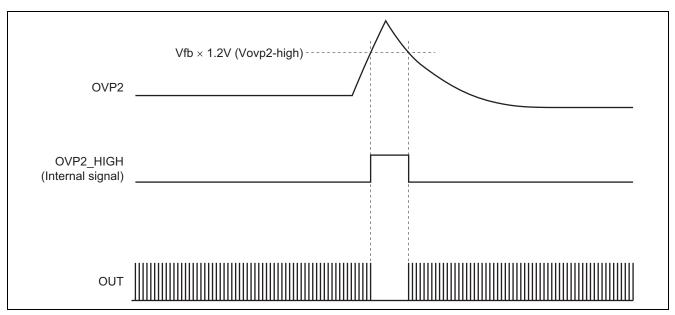


#### 7. Frequency Limiter

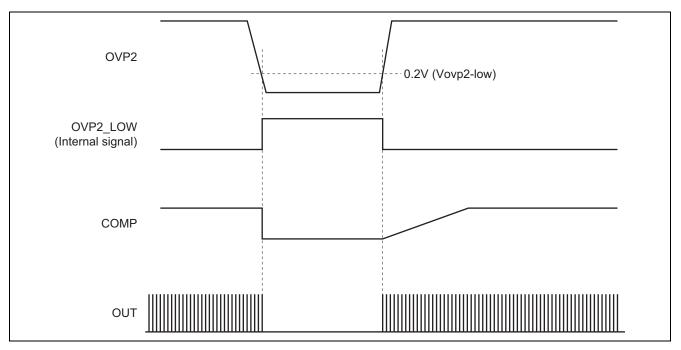




#### 8. Overvoltage Protection 2 (OVP2)

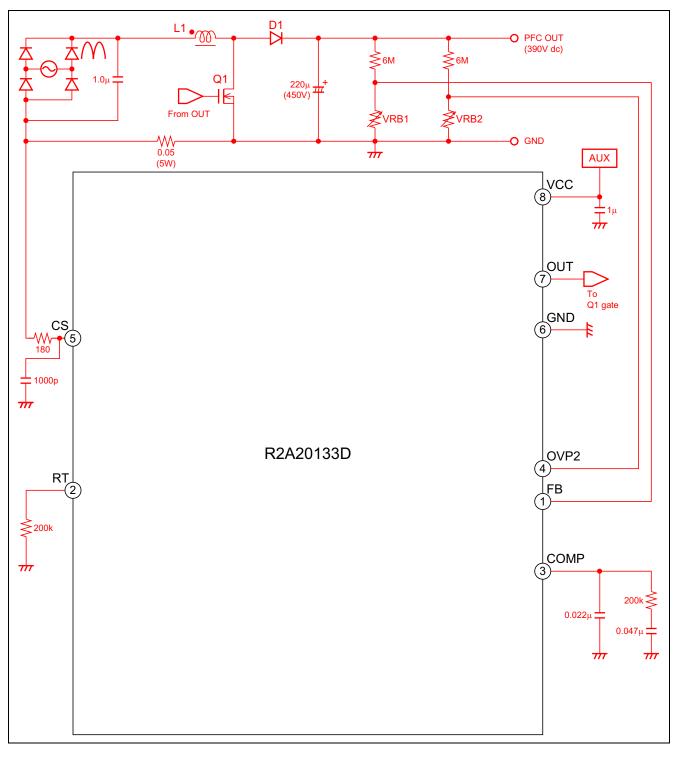


#### 9. OVP2 Low Detection



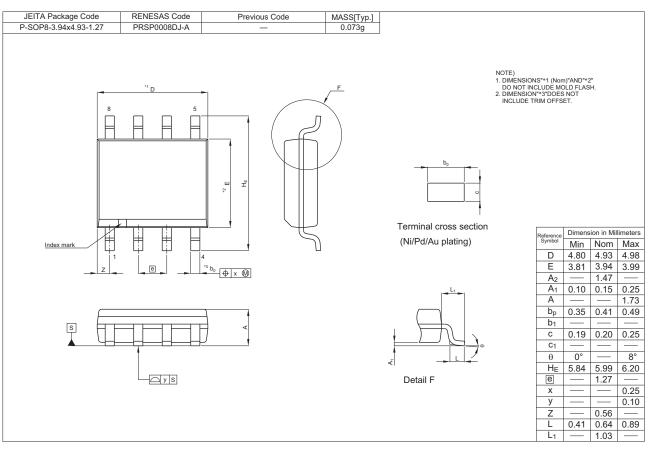


## System Diagram





## **Package Dimensions**





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